

PDTC114E series

NPN resistor-equipped transistors;
R1 = 10 k Ω , R2 = 10 k Ω

Rev. 12 — 21 December 2011

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistor (RET) family in small Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

| Type number | Package | | | PNP complement | Package configuration |
|-------------|---------|--------|----------|----------------|-----------------------|
| | NXP | JEITA | JEDEC | | |
| PDTC114EE | SOT416 | SC-75 | - | PDTA114EE | ultra small |
| PDTC114EM | SOT883 | SC-101 | - | PDTA114EM | leadless ultra small |
| PDTC114ET | SOT23 | - | TO-236AB | PDTA114ET | small |
| PDTC114EU | SOT323 | SC-70 | - | PDTA114EU | very small |

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Digital application in automotive and industrial segments
- Control of IC inputs
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

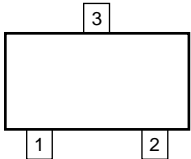
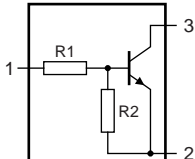
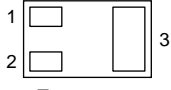
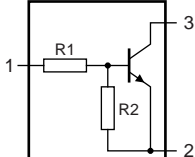
Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|---------------------------|------------|-----|-----|-----|------------|
| V _{CEO} | collector-emitter voltage | open base | - | - | 50 | V |
| I _O | output current | | - | - | 100 | mA |
| R1 | bias resistor 1 (input) | | 7 | 10 | 13 | k Ω |
| R2/R1 | bias resistor ratio | | 0.8 | 1.0 | 1.2 | |



2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|------------------------------|--------------------|---|---|
| SOT23; SOT323; SOT416 | | | |
| 1 | input (base) |  <p>006aaa144</p> |  <p>sym007</p> |
| 2 | GND (emitter) | | |
| 3 | output (collector) | | |
| SOT883 | | | |
| 1 | input (base) |  <p>Transparent top view</p> |  <p>sym007</p> |
| 2 | GND (emitter) | | |
| 3 | output (collector) | | |

3. Ordering information

Table 4. Ordering information

| Type number | Package | | |
|-------------|---------|---|---------|
| | Name | Description | Version |
| PDTC114EE | SC-75 | plastic surface-mounted package; 3 leads | SOT416 |
| PDTC114EM | SC-101 | leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm | SOT883 |
| PDTC114ET | - | plastic surface-mounted package; 3 leads | SOT23 |
| PDTC114EU | SC-70 | plastic surface-mounted package; 3 leads | SOT323 |

4. Marking

Table 5. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| PDTC114EE | 09 |
| PDTC114EM | DS |
| PDTC114ET | *16 |
| PDTC114EU | *09 |

[1] * = placeholder for manufacturing site code.

5. Limiting values

Table 6. Limiting values

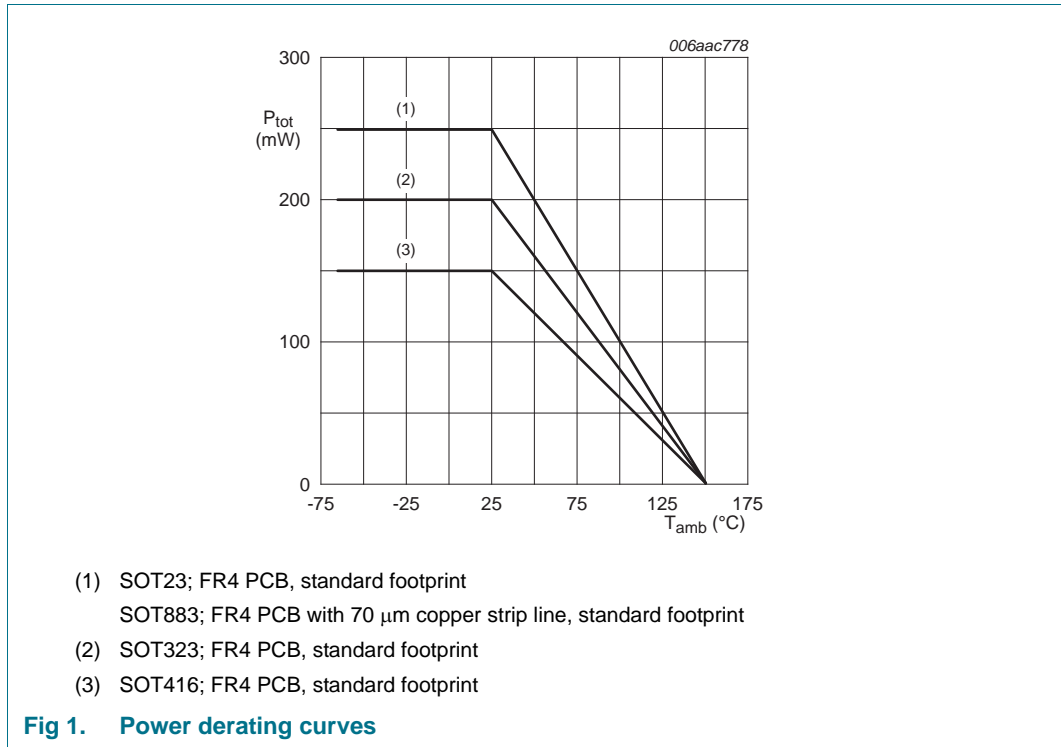
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit | |
|------------------|---------------------------|-------------------------------------|--------|------|------|----|
| V _{CBO} | collector-base voltage | open emitter | - | 50 | V | |
| V _{CEO} | collector-emitter voltage | open base | - | 50 | V | |
| V _{EBO} | emitter-base voltage | open collector | - | 10 | V | |
| V _I | input voltage | | | | | |
| | positive | | - | +40 | V | |
| | negative | | - | -10 | V | |
| I _O | output current | | - | 100 | mA | |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | 100 | mA | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | | |
| | PDTC114EE (SOT416) | | [1][2] | - | 150 | mW |
| | PDTC114EM (SOT883) | | [2][3] | - | 250 | mW |
| | PDTC114ET (SOT23) | | [1] | - | 250 | mW |
| | PDTC114EU (SOT323) | | [1] | - | 200 | mW |
| T _j | junction temperature | | - | 150 | °C | |
| T _{amb} | ambient temperature | | -65 | +150 | °C | |
| T _{stg} | storage temperature | | -65 | +150 | °C | |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



6. Thermal characteristics

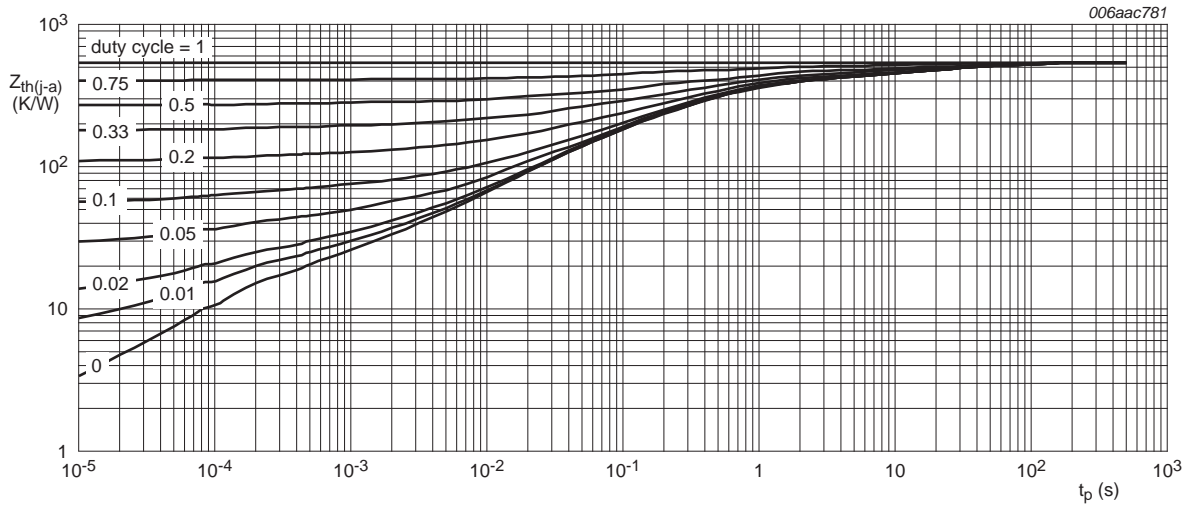
Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------------|---|-------------|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | | | |
| | PDTC114EE (SOT416) | [1][2] | - | - | 830 | K/W |
| | PDTC114EM (SOT883) | [2][3] | - | - | 500 | K/W |
| | PDTC114ET (SOT23) | [1] | - | - | 500 | K/W |
| | PDTC114EU (SOT323) | [1] | - | - | 625 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



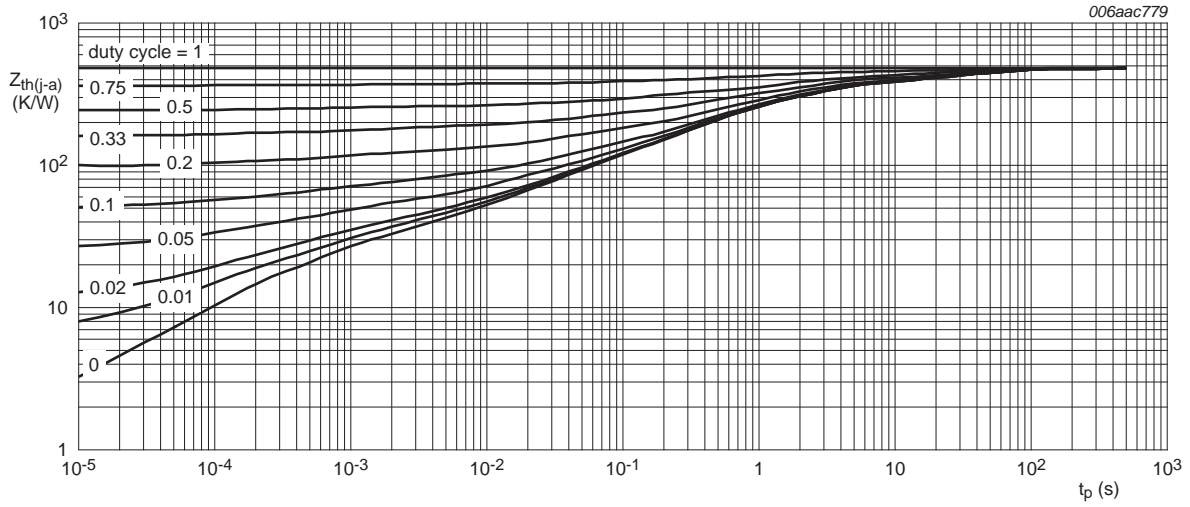
FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114EE (SOT416); typical values



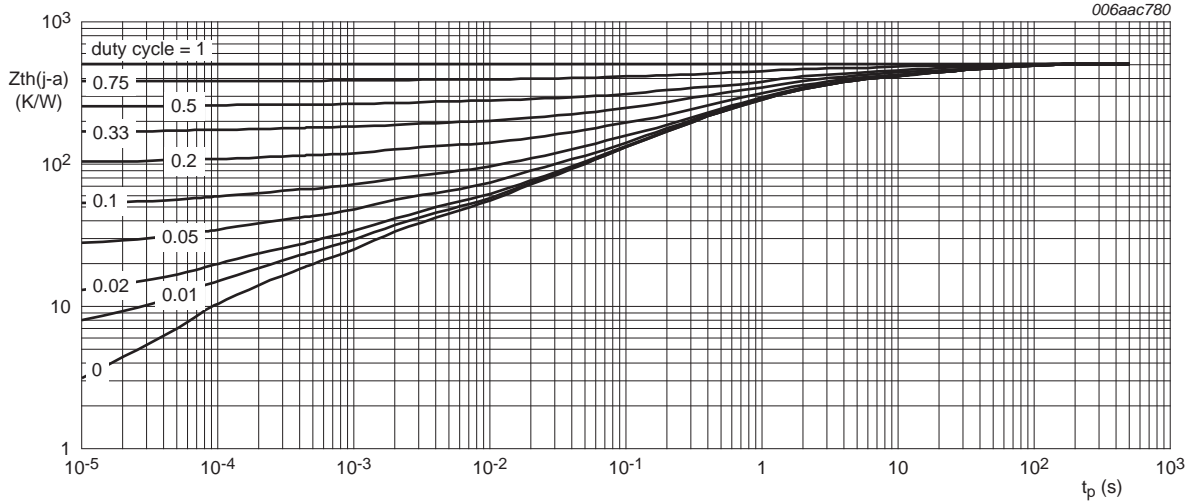
FR4 PCB, 70 μm copper strip line

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114EM (SOT883); typical values



FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114ET (SOT23); typical values



FR4 PCB, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114EU (SOT323); typical values

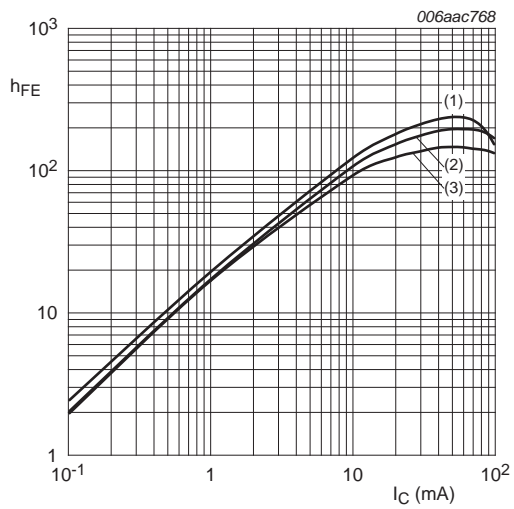
7. Characteristics

Table 8. Characteristics

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

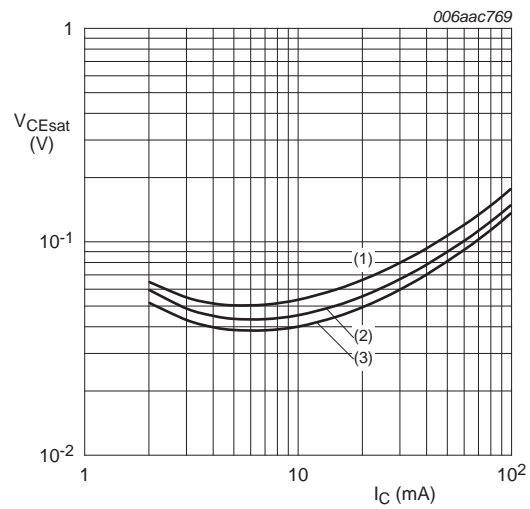
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--------------|--------------------------------------|--|-----|-----|-----|------|-----|
| I_{CBO} | collector-base cut-off current | $V_{CB} = 50\text{ V}; I_E = 0\text{ A}$ | - | - | 100 | nA | |
| I_{CEO} | collector-emitter cut-off current | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}$ | - | - | 1 | μA | |
| | | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}; T_j = 150\text{ °C}$ | - | - | 5 | μA | |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = 5\text{ V}; I_C = 0\text{ A}$ | - | - | 400 | μA | |
| h_{FE} | DC current gain | $V_{CE} = 5\text{ V}; I_C = 5\text{ mA}$ | 30 | - | - | | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$ | - | - | 150 | mV | |
| $V_{I(off)}$ | off-state input voltage | $V_{CE} = 5\text{ V}; I_C = 100\text{ μA}$ | - | 1.1 | 0.8 | V | |
| $V_{I(on)}$ | on-state input voltage | $V_{CE} = 0.3\text{ V}; I_C = 10\text{ mA}$ | 2.5 | 1.8 | - | V | |
| R1 | bias resistor 1 (input) | | 7 | 10 | 13 | kΩ | |
| R2/R1 | bias resistor ratio | | 0.8 | 1.0 | 1.2 | | |
| C_c | collector capacitance | $V_{CB} = 10\text{ V}; I_E = I_C = 0\text{ A}; f = 1\text{ MHz}$ | - | - | 2.5 | pF | |
| f_T | transition frequency | $V_{CE} = 5\text{ V}; I_C = 10\text{ mA}; f = 100\text{ MHz}$ | [1] | - | 230 | - | MHz |

[1] Characteristics of built-in transistor.



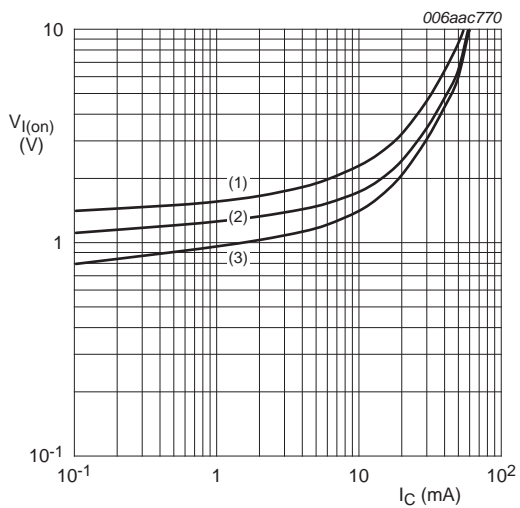
$V_{CE} = 5\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig 6. DC current gain as a function of collector current; typical values



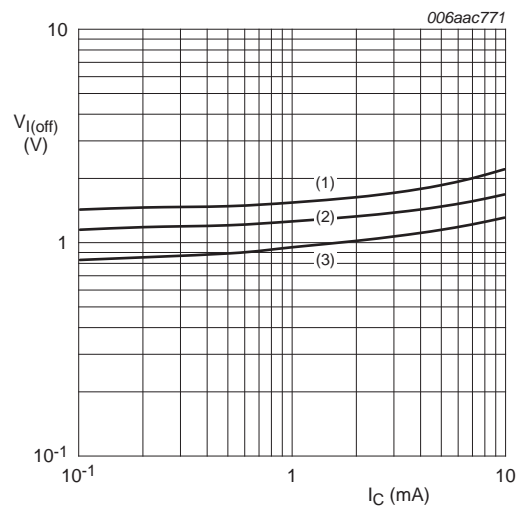
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



$V_{CE} = 0.3\text{ V}$
 (1) $T_{amb} = -40\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig 8. On-state input voltage as a function of collector current; typical values



$V_{CE} = 5\text{ V}$
 (1) $T_{amb} = -40\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig 9. Off-state input voltage as a function of collector current; typical values

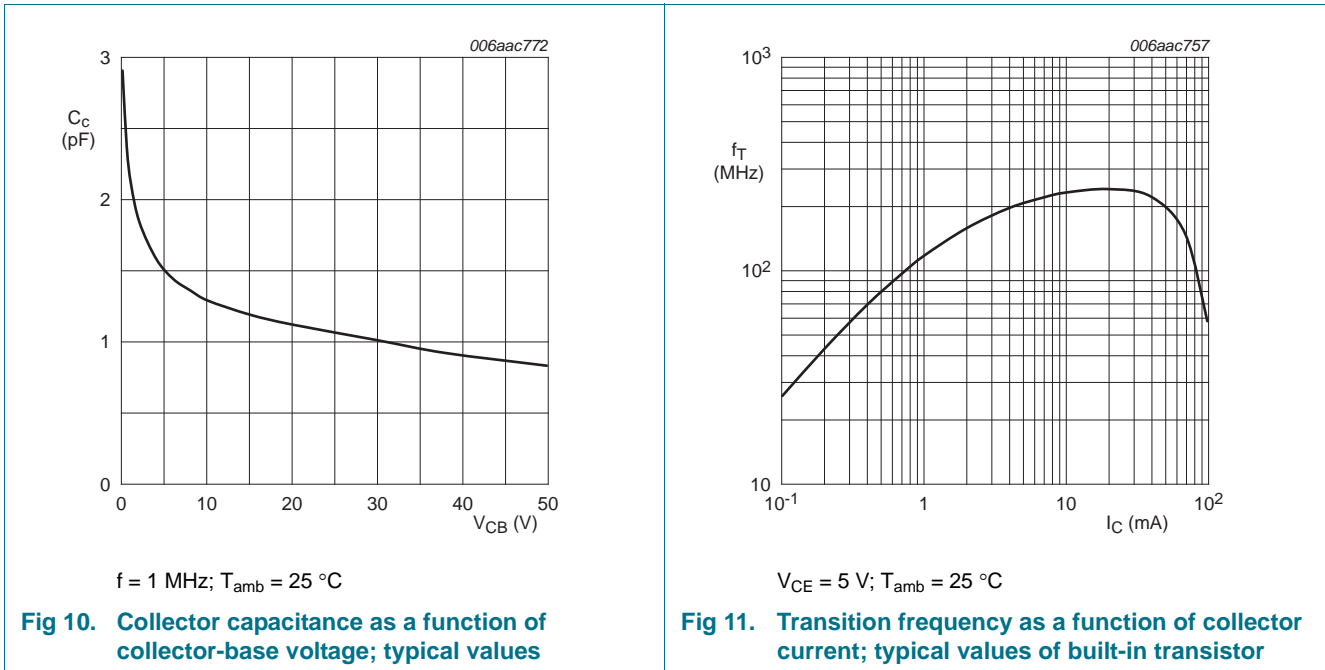


Fig 10. Collector capacitance as a function of collector-base voltage; typical values

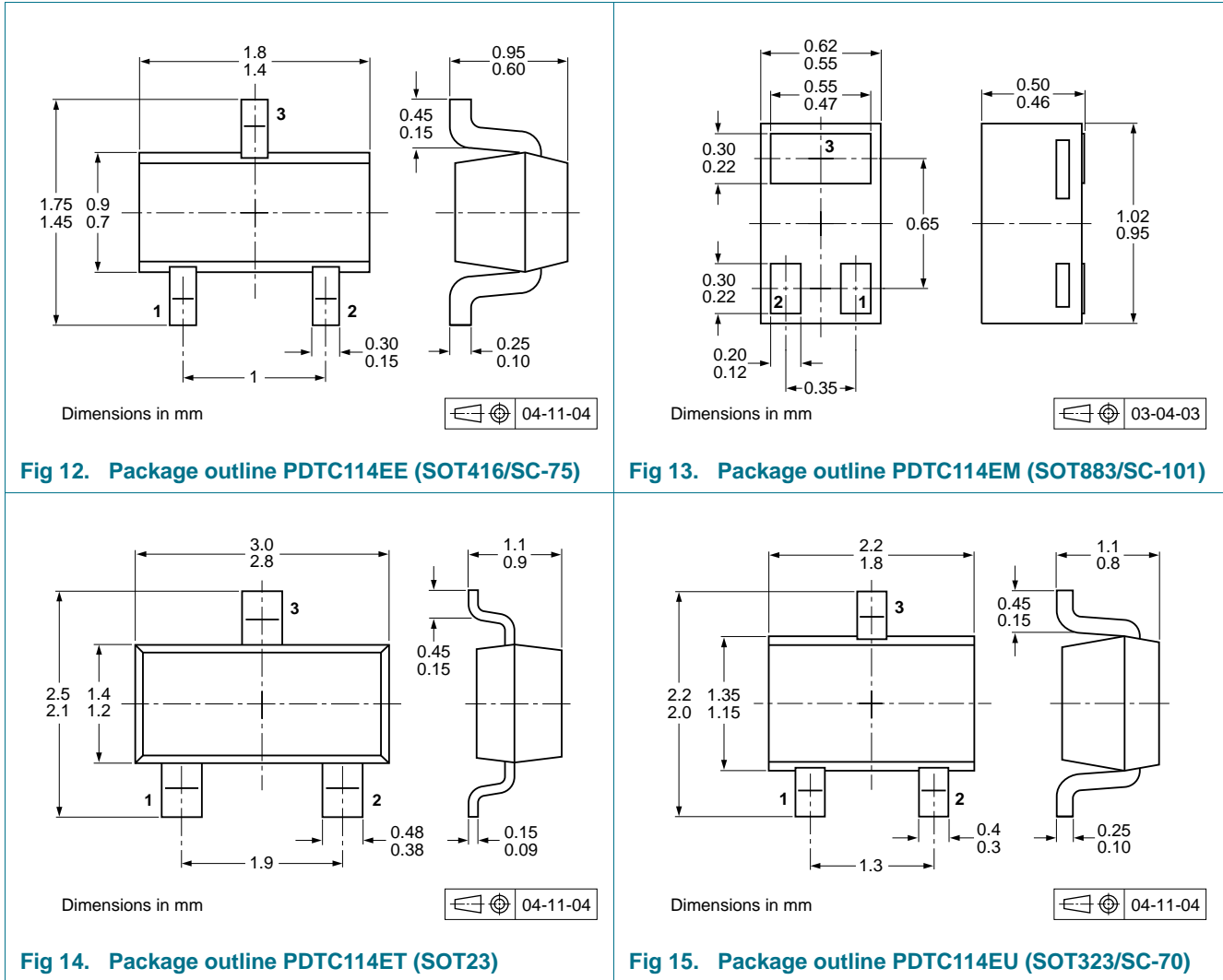
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

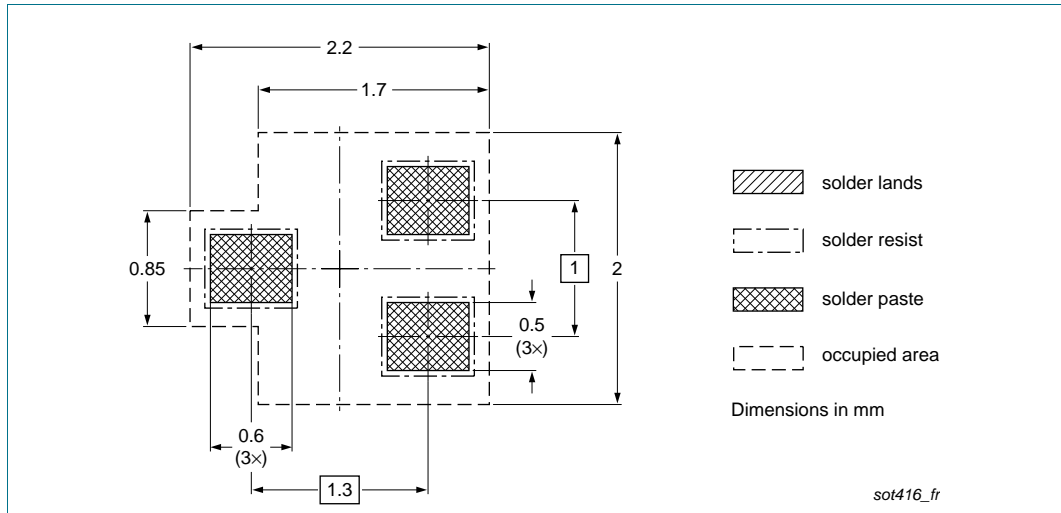
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

| Type number | Package | Description | Packing quantity | |
|-------------|---------|--------------------------------|------------------|-------|
| | | | 3000 | 10000 |
| PDTC114EE | SOT416 | 4 mm pitch, 8 mm tape and reel | -115 | -135 |
| PDTC114EM | SOT883 | 2 mm pitch, 8 mm tape and reel | - | -315 |
| PDTC114ET | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | -235 |
| PDTC114EU | SOT323 | 4 mm pitch, 8 mm tape and reel | -115 | -135 |

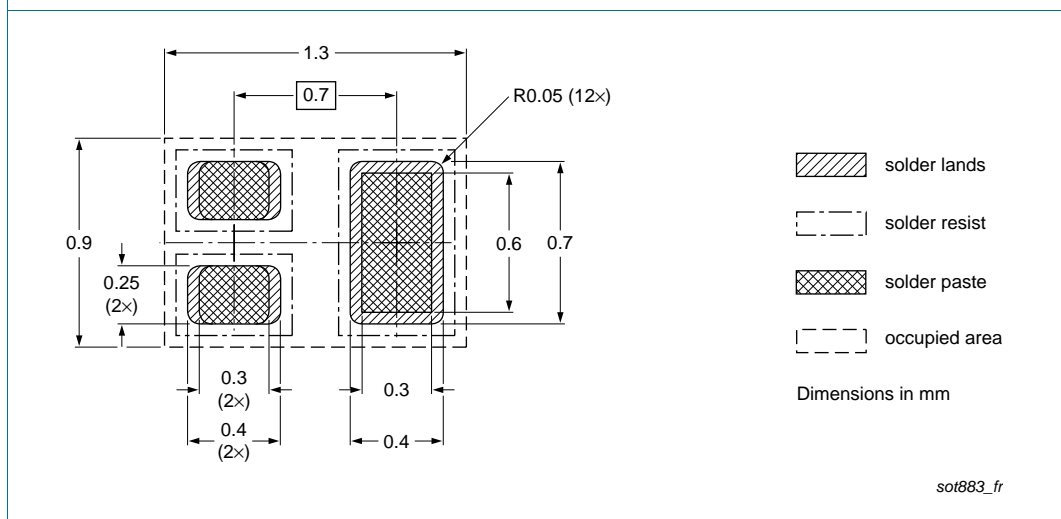
[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering



Reflow soldering is the only recommended soldering method.

Fig 16. Reflow soldering footprint PDTC114EE (SOT416/SC-75)



Reflow soldering is the only recommended soldering method.

Fig 17. Reflow soldering footprint PDTC114EM (SOT883/SC-101)

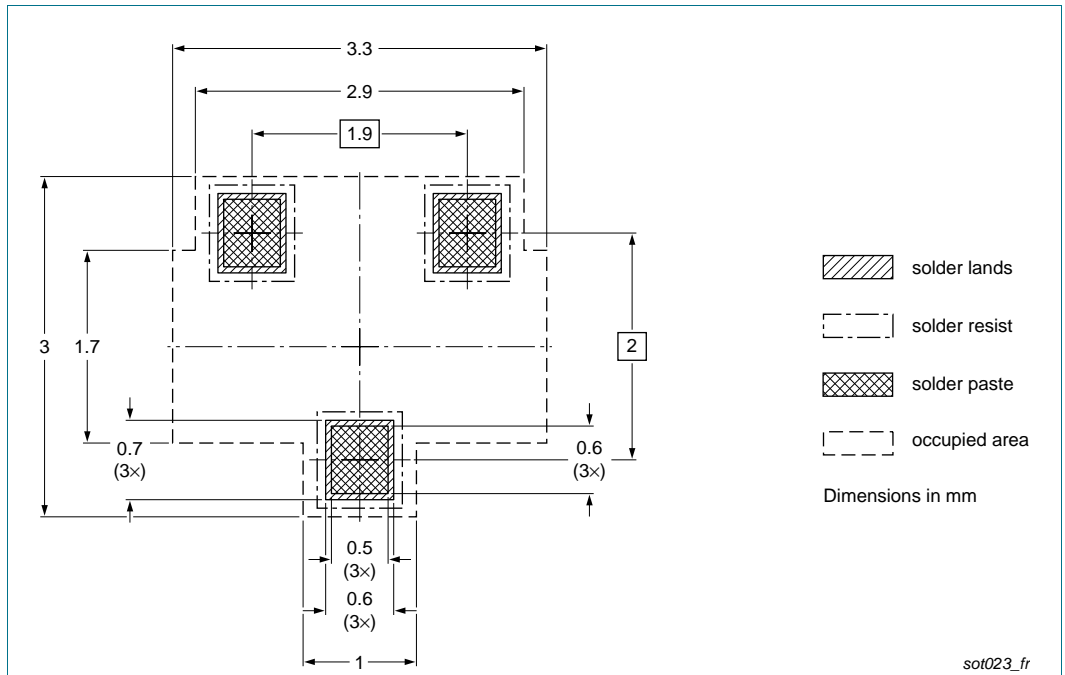


Fig 18. Reflow soldering footprint PDTC114ET (SOT23)

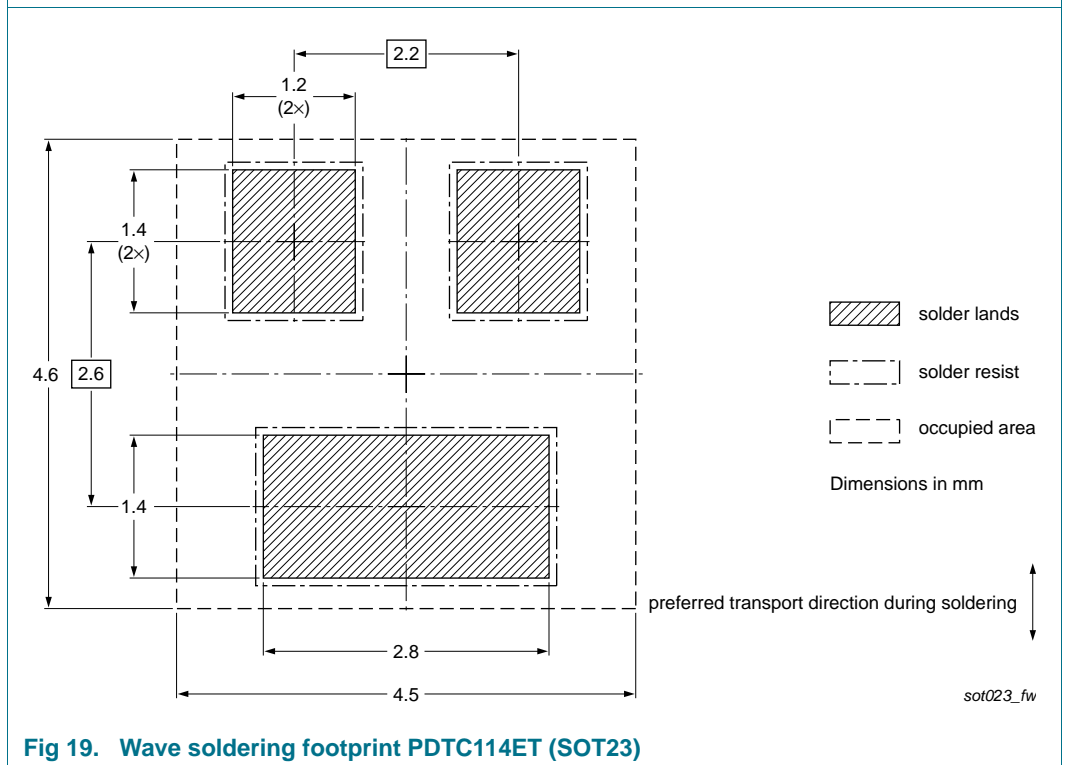


Fig 19. Wave soldering footprint PDTC114ET (SOT23)

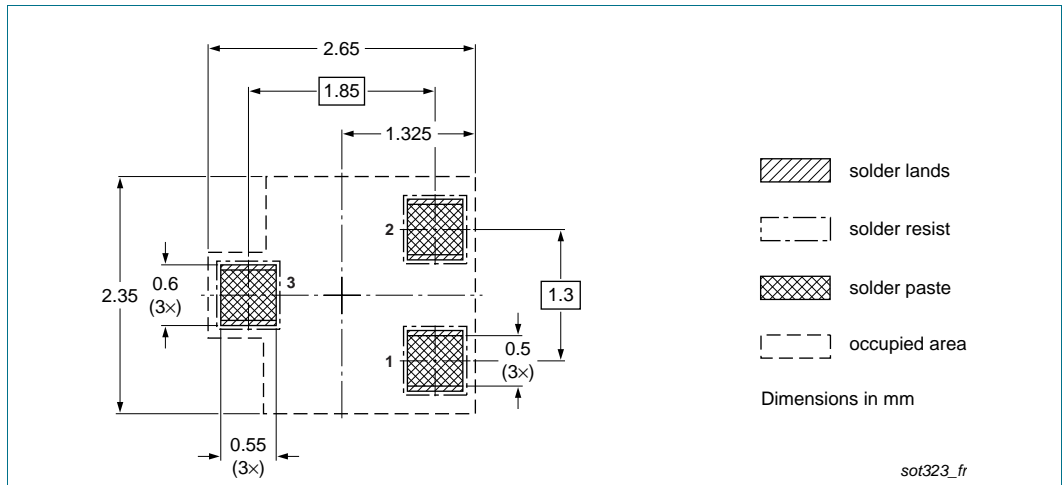


Fig 20. Reflow soldering footprint PDTC114EU (SOT323/SC-70)

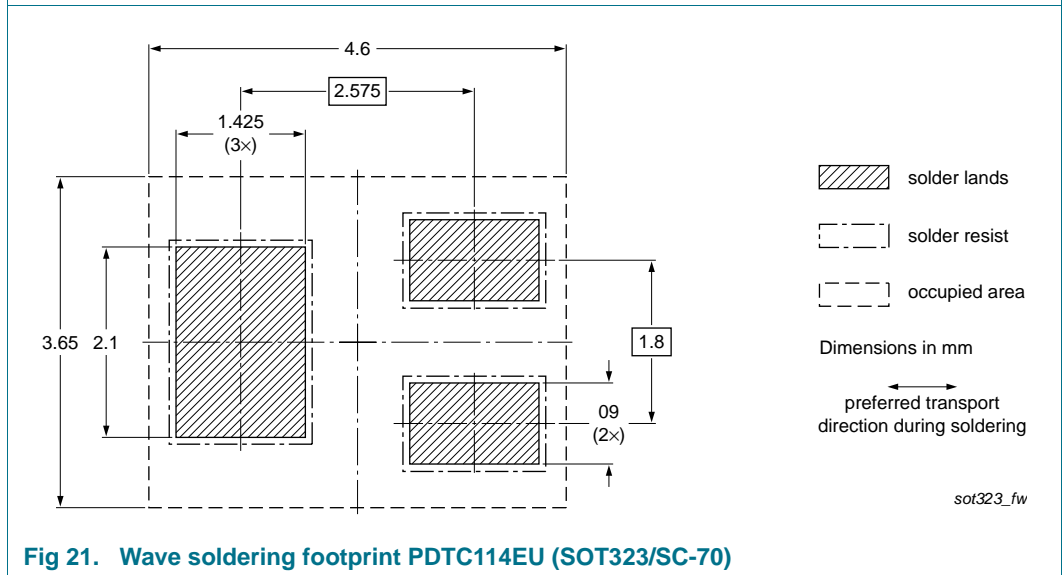


Fig 21. Wave soldering footprint PDTC114EU (SOT323/SC-70)

12. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------------|--|-----------------------|---------------|----------------------|
| PDTC114E_SER v.12 | 20111221 | Product data sheet | - | PDTC114E_SER v.11 |
| Modifications: | • Figure 3 and 5 : corrected | | | |
| PDTC114E_SER v.11 | 20111121 | Product data sheet | - | PDTC114E_SERIES v.10 |
| PDTC114E_SERIES v.10 | 20040805 | Product specification | - | PDTC114E_SERIES v.9 |
| PDTC114E_SERIES v.9 | 20030410 | Product specification | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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